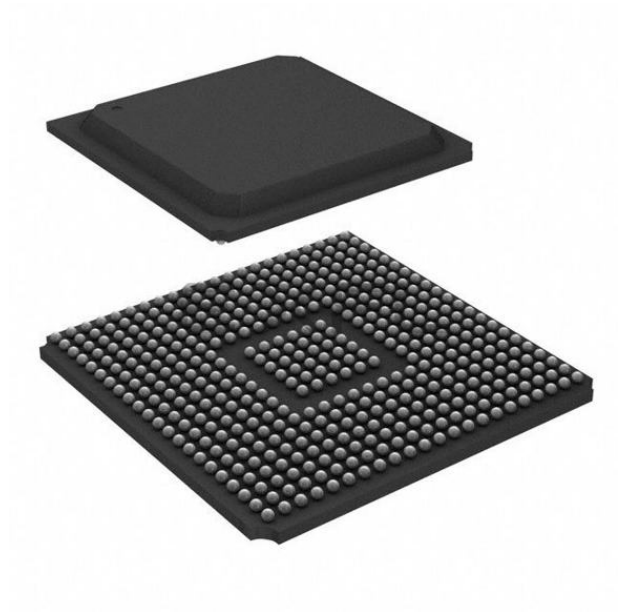
AMD Xilinx - XCV300E-7FG456C Datasheet



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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	1536
Number of Logic Elements/Cells	6912
Total RAM Bits	131072
Number of I/O	312
Number of Gates	411955
Voltage - Supply	1.71V ~ 1.89V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	456-BBGA
Supplier Device Package	456-FBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xcv300e-7fg456c

forces a storage element into the initialization state specified for it in the configuration. BY forces it into the opposite state. Alternatively, these signals can be configured to operate asynchronously. All of the control signals are independently invertible, and are shared by the two flip-flops within the slice.

Additional Logic

The F5 multiplexer in each slice combines the function generator outputs. This combination provides either a function generator that can implement any 5-input function, a 4:1 multiplexer, or selected functions of up to nine inputs.

Similarly, the F6 multiplexer combines the outputs of all four function generators in the CLB by selecting one of the F5-multiplexer outputs. This permits the implementation of any 6-input function, an 8:1 multiplexer, or selected functions of up to 19 inputs.

Each CLB has four direct feedthrough paths, two per slice. These paths provide extra data input lines or additional local routing that does not consume logic resources.

Arithmetic Logic

Dedicated carry logic provides fast arithmetic carry capability for high-speed arithmetic functions. The Virtex-E CLB supports two separate carry chains, one per Slice. The height of the carry chains is two bits per CLB.

The arithmetic logic includes an XOR gate that allows a 2-bit full adder to be implemented within a slice. In addition, a dedicated AND gate improves the efficiency of multiplier implementation. The dedicated carry path can also be used to cascade function generators for implementing wide logic functions.

BUFTs

Each Virtex-E CLB contains two 3-state drivers (BUFTs) that can drive on-chip buses. See **Dedicated Routing**. Each Virtex-E BUFT has an independent 3-state control pin and an independent input pin.

Block SelectRAM

Virtex-E FPGAs incorporate large block SelectRAM memories. These complement the Distributed SelectRAM memories that provide shallow RAM structures implemented in CLBs.

Block SelectRAM memory blocks are organized in columns, starting at the left (column 0) and right outside edges and inserted every 12 CLB columns (see notes for smaller devices). Each memory block is four CLBs high, and each memory column extends the full height of the chip, immediately adjacent (to the right, except for column 0) of the CLB column locations indicated in Table 3.

Table 3: **CLB/Block RAM Column Locations**

XCV Device /Col.	0	12	24	36	48	60	72	84	96	108	120	138	156
50E	Columns 0, 6, 18, & 24												
100E	Columns 0, 12, 18, & 30												
200E	Columns 0, 12, 30, & 42												
300E	√	√		√	√								
400E	√	√			√	√							
600E	√	√	√		√	√	√						
1000E	√	√	√				√	√	√				
1600E	√	√	√	√			√	√	√	√			
2000E	√	√	√	√				√	√	√	√		
2600E	√	√	√	√					√	√	√	√	
3200E	√	√	√	√						√	√	√	√

Table 4 shows the amount of block SelectRAM memory that is available in each Virtex-E device.

Table 4: **Virtex-E Block SelectRAM Amounts**

Virtex-E Device	# of Blocks	Block SelectRAM Bits
XCV50E	16	65,536
XCV100E	20	81,920
XCV200E	28	114,688
XCV300E	32	131,072
XCV400E	40	163,840
XCV600E	72	294,912
XCV1000E	96	393,216
XCV1600E	144	589,824
XCV2000E	160	655,360
XCV2600E	184	753,664
XCV3200E	208	851,968

As illustrated in Figure 6, each block SelectRAM cell is a fully synchronous dual-ported (True Dual Port) 4096-bit RAM with independent control signals for each port. The data widths of the two ports can be configured independently, providing built-in bus-width conversion.

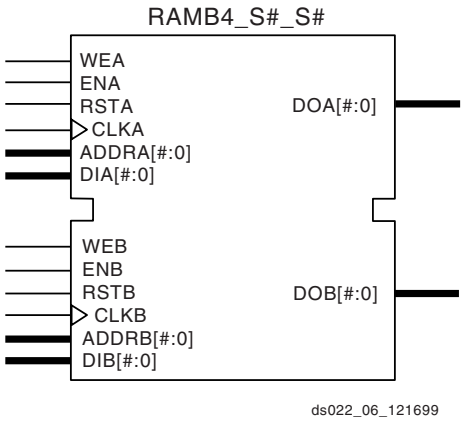

Figure 6: **Dual-Port Block SelectRAM**

Table 5 shows the depth and width aspect ratios for the block SelectRAM. The Virtex-E block SelectRAM also includes dedicated routing to provide an efficient interface with both CLBs and other block SelectRAMs. Refer to XAPP130 for block SelectRAM timing waveforms.

Table 5: **Block SelectRAM Port Aspect Ratios**

Width	Depth	ADDR Bus	Data Bus
1	4096	ADDR<11:0>	DATA<0>
2	2048	ADDR<10:0>	DATA<1:0>
4	1024	ADDR<9:0>	DATA<3:0>
8	512	ADDR<8:0>	DATA<7:0>
16	256	ADDR<7:0>	DATA<15:0>

Programmable Routing Matrix

It is the longest delay path that limits the speed of any worst-case design. Consequently, the Virtex-E routing architecture and its place-and-route software were defined in a joint optimization process. This joint optimization minimizes long-path delays, and consequently, yields the best system performance.

The joint optimization also reduces design compilation times because the architecture is software-friendly. Design cycles are correspondingly reduced due to shorter design iteration times.

Local Routing

The VersaBlock provides local routing resources (see Figure 7), providing three types of connections:

- Interconnections among the LUTs, flip-flops, and GRM
- Internal CLB feedback paths that provide high-speed connections to LUTs within the same CLB, chaining them together with minimal routing delay
- Direct paths that provide high-speed connections between horizontally adjacent CLBs, eliminating the delay of the GRM.

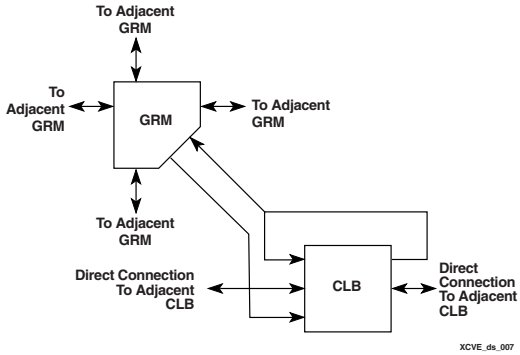

Figure 7: **Virtex-E Local Routing**

General Purpose Routing

Most Virtex-E signals are routed on the general purpose routing, and consequently, the majority of interconnect resources are associated with this level of the routing hierarchy. General-purpose routing resources are located in horizontal and vertical routing channels associated with the CLB rows and columns and are as follows:

- Adjacent to each CLB is a General Routing Matrix (GRM). The GRM is the switch matrix through which horizontal and vertical routing resources connect, and is also the means by which the CLB gains access to the general purpose routing.
- 24 single-length lines route GRM signals to adjacent GRMs in each of the four directions.
- 72 buffered Hex lines route GRM signals to another GRMs six-blocks away in each one of the four directions. Organized in a staggered pattern, Hex lines are driven only at their endpoints. Hex-line signals can be accessed either at the endpoints or at the midpoint (three blocks from the source). One third of the Hex lines are bidirectional, while the remaining ones are uni-directional.
- 12 Longlines are buffered, bidirectional wires that distribute signals across the device quickly and efficiently. Vertical Longlines span the full height of the device, and horizontal ones span the full width of the device.

I/O Routing

Virtex-E devices have additional routing resources around their periphery that form an interface between the CLB array and the IOBs. This additional routing, called the VersaRing, facilitates pin-swapping and pin-locking, such that logic redesigns can adapt to existing PCB layouts. Time-to-market is reduced, since PCBs and other system components can be manufactured while the logic design is still in progress.

Because any single DLL can access only two BUFGs at most, any additional output clock signals must be routed from the DLL in this example on the high speed backbone routing.

The dll_2x files in the **xapp132.zip** file show the VHDL and Verilog implementation of this circuit.

Virtex-E 4x Clock

Two DLLs located in the same half-edge (top-left, top-right, bottom-right, bottom-left) can be connected together, without using a BUFG between the CLKDLLs, to generate a 4x clock as shown in Figure 30. Virtex-E devices, like the Virtex devices, have four clock networks that are available for internal deskewing of the clock. Each of the eight DLLs have access to two of the four clock networks. Although all the DLLs can be used for internal deskewing, the presence of two GCLKBUFs on the top and two on the bottom indicate that only two of the four DLLs on the top (and two of the four DLLs on the bottom) can be used for this purpose.

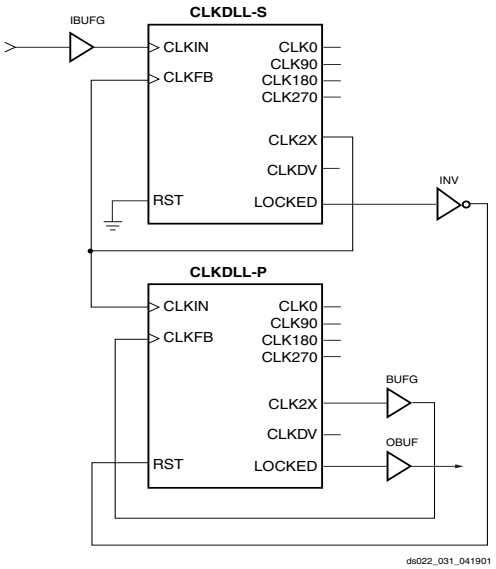

Figure 30: **DLL Generation of 4x Clock in Virtex-E Devices**

The dll_4xe files in the xapp132.zip file show the DLL implementation in Verilog for Virtex-E devices. These files can be found at:

ftp://ftp.xilinx.com/pub/applications/xapp/xapp132.zip

Using Block SelectRAM+ Features

The Virtex FPGA Series provides dedicated blocks of on-chip, true dual-read/write port synchronous RAM, with 4096 memory cells. Each port of the block SelectRAM+ memory can be independently configured as a read/write port, a read port, a write port, and can be configured to a specific data width. The block SelectRAM+ memory offers new capabilities allowing the FPGA designer to simplify designs.

Operating Modes

VIrtex-E block SelectRAM+ memory supports two operating modes:

- Read Through
- Write Back

Read Through (one clock edge)

The read address is registered on the read port clock edge and data appears on the output after the RAM access time. Some memories might place the latch/register at the outputs, depending on whether a faster clock-to-out versus set-up time is desired. This is generally considered to be an inferior solution, since it changes the read operation to an asynchronous function with the possibility of missing an address/control line transition during the generation of the read pulse clock.

Write Back (one clock edge)

The write address is registered on the write port clock edge and the data input is written to the memory and mirrored on the output.

Block SelectRAM+ Characteristics

- All inputs are registered with the port clock and have a set-up to clock timing specification.
- All outputs have a read through or write back function depending on the state of the port WE pin. The outputs relative to the port clock are available after the clock-to-out timing specification.
- The block SelectRAMs are true SRAM memories and do not have a combinatorial path from the address to the output. The LUT SelectRAM+ cells in the CLBs are still available with this function.
- The ports are completely independent from each other (*i.e.,* clocking, control, address, read/write function, and data width) without arbitration.
- A write operation requires only one clock edge.
- A read operation requires only one clock edge.

The output ports are latched with a self timed circuit to guarantee a glitch free read. The state of the output port does not change until the port executes another read or write operation.

Library Primitives

Figure 31 and Figure 32 show the two generic library block SelectRAM+ primitives. Table 14 describes all of the available primitives for synthesis and simulation.

Data Output Bus—DO[A|B]<#:0>

The data out bus reflects the contents of the memory cells referenced by the address bus at the last active clock edge. During a write operation, the data out bus reflects the data in bus. The width of this bus equals the width of the port. The allowed widths appear in Table 15.

Inverting Control Pins

The four control pins (CLK, EN, WE and RST) for each port have independent inversion control as a configuration option.

Address Mapping

Each port accesses the same set of 4096 memory cells using an addressing scheme dependent on the width of the port.

The physical RAM location addressed for a particular width are described in the following formula (of interest only when the two ports use different aspect ratios).

$$Start = ((ADDR_{port} + 1) * Width_{port}) - 1$$

$$End = ADDR_{port} * Width_{port}$$

Conflict Resolution

The block SelectRAM+ memory is a true dual-read/write port RAM that allows simultaneous access of the same memory cell from both ports. When one port writes to a given memory cell, the other port must not address that memory cell (for a write or a read) within the clock-to-clock setup window. The following lists specifics of port and memory cell write conflict resolution.

- If both ports write to the same memory cell simultaneously, violating the clock-to-clock setup requirement, consider the data stored as invalid.
- If one port attempts a read of the same memory cell the other simultaneously writes, violating the clock-to-clock setup requirement, the following occurs.
  - The write succeeds
  - The data out on the writing port accurately reflects the data written.
  - The data out on the reading port is invalid.

Conflicts do not cause any physical damage.

Table 16 shows low order address mapping for each port width.

Table 16: **Port Address Mapping**

Port Width	Port Addresses																
1	4095...	15	14	13	12	11	10	09	08	07	06	05	04	03	02	01	00
2	2047...	07		06		05		04		03		02		01		00	
4	1023...	03				02				01				00			
8	511...	01								00							
16	255...	00															

Creating Larger RAM Structures

The block SelectRAM+ columns have specialized routing to allow cascading blocks together with minimal routing delays. This achieves wider or deeper RAM structures with a smaller timing penalty than when using normal routing channels.

Location Constraints

Block SelectRAM+ instances can have LOC properties attached to them to constrain the placement. The block SelectRAM+ placement locations are separate from the CLB location naming convention, allowing the LOC properties to transfer easily from array to array.

The LOC properties use the following form.

LOC = RAMB4_R#C#

RAMB4_R0C0 is the upper left RAMB4 location on the device.

Single Port Timing

Figure 33 shows a timing diagram for a single port of a block SelectRAM+ memory. The block SelectRAM+ AC switching characteristics are specified in the data sheet. The block SelectRAM+ memory is initially disabled.

At the first rising edge of the CLK pin, the ADDR, DI, EN, WE, and RST pins are sampled. The EN pin is High and the WE pin is Low indicating a read operation. The DO bus contains the contents of the memory location, 0x00, as indicated by the ADDR bus.

At the second rising edge of the CLK pin, the ADDR, DI, EN, WR, and RST pins are sampled again. The EN and WE pins are High indicating a write operation. The DO bus mirrors the DI bus. The DI bus is written to the memory location 0x0F.

At the third rising edge of the CLK pin, the ADDR, DI, EN, WR, and RST pins are sampled again. The EN pin is High and the WE pin is Low indicating a read operation. The DO bus contains the contents of the memory location 0x7E as indicated by the ADDR bus.

At the fourth rising edge of the CLK pin, the ADDR, DI, EN, WR, and RST pins are sampled again. The EN pin is Low

CLB Distributed RAM Switching Characteristics

Description	Symbol	Speed Grade(1)				Units
		Min	-8	-7	-6	
Sequential Delays						
Clock CLK to X/Y outputs (WE active) 16 x 1 mode	$T_{SHCKO16}$	0.67	1.38	1.5	1.7	ns, max
Clock CLK to X/Y outputs (WE active) 32 x 1 mode	$T_{SHCKO32}$	0.84	1.66	1.9	2.1	ns, max
Shift-Register Mode Clock CLK to X/Y outputs	T_{REG}	1.25	2.39	2.9	3.2	ns, max
Setup and Hold Times before/after Clock CLK						
F/G address inputs	T_{AS}/T_{AH}	0.19 / 0	0.38 / 0	0.42 / 0	0.47 / 0	ns, min
BX/BY data inputs (DIN)	T_{DS}/T_{DH}	0.44 / 0	0.87 / 0	0.97 / 0	1.09 / 0	ns, min
SR input (WE)	T_{WS}/T_{WH}	0.29 / 0	0.57 / 0	0.7 / 0	0.8 / 0	ns, min
Clock CLK						
Minimum Pulse Width, High	T_{WPH}	0.96	1.9	2.1	2.4	ns, min
Minimum Pulse Width, Low	T_{WPL}	0.96	1.9	2.1	2.4	ns, min
Minimum clock period to meet address write cycle time	T_{WC}	1.92	3.8	4.2	4.8	ns, min
Shift-Register Mode						
Minimum Pulse Width, High	T_{SRPH}	1.0	1.9	2.1	2.4	ns, min
Minimum Pulse Width, Low	T_{SRPL}	1.0	1.9	2.1	2.4	ns, min

Notes:
1. A Zero “0” Hold Time listing indicates no hold time or a negative hold time. Negative values can not be guaranteed “best-case”, but if a “0” is listed, there is no positive hold time.

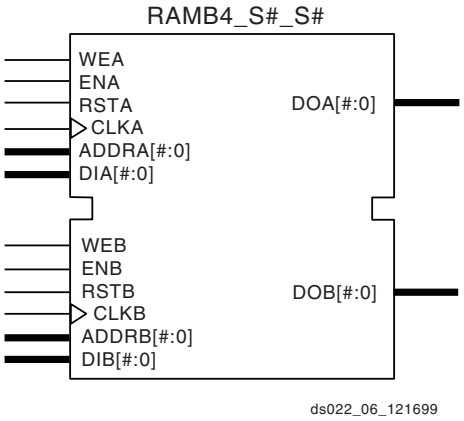

Figure 3: **Dual-Port Block SelectRAM**

Block RAM Switching Characteristics

Description	Symbol	Speed Grade(1)				Units
		Min	-8	-7	-6	
Sequential Delays						
Clock CLK to DOUT output	T_{BCKO}	0.63	2.46	3.1	3.5	ns, max
Setup and Hold Times before Clock CLK						
ADDR inputs	T_{BACK}/T_{BCKA}	0.42 / 0	0.9 / 0	1.0 / 0	1.1 / 0	ns, min
DIN inputs	T_{BDCK}/T_{BCKD}	0.42 / 0	0.9 / 0	1.0 / 0	1.1 / 0	ns, min
EN input	T_{BECK}/T_{BCKE}	0.97 / 0	2.0 / 0	2.2 / 0	2.5 / 0	ns, min
RST input	T_{BRCK}/T_{BCKR}	0.9 / 0	1.8 / 0	2.1 / 0	2.3 / 0	ns, min
WEN input	T_{BWCK}/T_{BCKW}	0.86 / 0	1.7 / 0	2.0 / 0	2.2 / 0	ns, min
Clock CLK						
Minimum Pulse Width, High	T_{BPWH}	0.6	1.2	1.35	1.5	ns, min
Minimum Pulse Width, Low	T_{BPWL}	0.6	1.2	1.35	1.5	ns, min
CLKA -> CLKB setup time for different ports	T_{BCCS}	1.2	2.4	2.7	3.0	ns, min

Notes:
1. A Zero “0” Hold Time listing indicates no hold time or a negative hold time. Negative values can not be guaranteed “best-case”, but if a “0” is listed, there is no positive hold time.

TBUF Switching Characteristics

Description	Symbol	Speed Grade				Units
		Min	-8	-7	-6	
Combinatorial Delays						
IN input to OUT output	T_{IO}	0.0	0.0	0.0	0 .0	ns, max
TRI input to OUT output high-impedance	T_{OFF}	0.05	0.092	0.10	0.11	ns, max
TRI input to valid data on OUT output	T_{ON}	0.05	0.092	0.10	0.11	ns, max

JTAG Test Access Port Switching Characteristics

Description	Symbol	Value	Units
TMS and TDI Setup times before TCK	T_{TAPTK}	4.0	ns, min
TMS and TDI Hold times after TCK	T_{TCKTAP}	2.0	ns, min
Output delay from clock TCK to output TDO	T_{TCKTDO}	11.0	ns, max
Maximum TCK clock frequency	F_{TCK}	33	MHz, max

Revision History

The following table shows the revision history for this document.

Date	Version	Revision
12/7/99	1.0	Initial Xilinx release.
1/10/00	1.1	Re-released with spd.txt v. 1.18, FG860/900/1156 package information, and additional DLL, Select RAM and SelectI/O information.
1/28/00	1.2	Added Delay Measurement Methodology table, updated SelectI/O section, Figures 30, 54, & 55, text explaining Table 5, T_{BYP} values, buffered Hex Line info, p. 8, I/O Timing Measurement notes, notes for Tables 15, 16, and corrected F1156 pinout table footnote references.
2/29/00	1.3	Updated pinout tables, V_{CC} page 20, and corrected Figure 20.
5/23/00	1.4	Correction to table on p. 22.
7/10/00	1.5	• Numerous minor edits. • Data sheet upgraded to Preliminary. • Preview -8 numbers added to **Virtex-E Electrical Characteristics** tables.
8/1/00	1.6	• Reformatted entire document to follow new style guidelines. • Changed speed grade values in tables on pages 35-37.
9/20/00	1.7	• Min values added to **Virtex-E Electrical Characteristics** tables. • XCV2600E and XCV3200E numbers added to **Virtex-E Electrical Characteristics** tables (Module 3). • Corrected user I/O count for XCV100E device in Table 1 (Module 1). • Changed several pins to “No Connect in the XCV100E“ and removed duplicate V_{CCINT} pins in Table ~ (Module 4). • Changed pin J10 to “No connect in XCV600E” in Table 74 (Module 4). • Changed pin J30 to “VREF option only in the XCV600E” in Table 74 (Module 4). • Corrected pair 18 in Table 75 (Module 4) to be “AO in the XCV1000E, XCV1600E“.
11/20/00	1.8	• Upgraded speed grade -8 numbers in **Virtex-E Electrical Characteristics** tables to Preliminary. • Updated minimums in Table 13 and added notes to Table 14. • Added to note 2 to **Absolute Maximum Ratings**. • Changed speed grade -8 numbers for $T_{SHCKO32}$, T_{REG}, T_{BCCS}, and T_{ICKOF} • Changed all minimum hold times to –0.4 under **Global Clock Set-Up and Hold for LVTTL Standard, with DLL**. • Revised maximum T_{DLLPW} in -6 speed grade for **DLL Timing Parameters**. • Changed GCLK0 to BA22 for FG860 package in Table 46.
2/12/01	1.9	• Revised footnote for Table 14. • Added numbers to **Virtex-E Electrical Characteristics** tables for XCV1000E and XCV2000E devices. • Updated Table 27 and Table 78 to include values for XCV400E and XCV600E devices. • Revised Table 62 to include pinout information for the XCV400E and XCV600E devices in the BG560 package. • Updated footnotes 1 and 2 for Table 76 to include XCV2600E and XCV3200E devices.
4/02/01	2.0	• Updated numerous values in **Virtex-E Switching Characteristics** tables. • Converted data sheet to modularized format. See the **Virtex-E Data Sheet** section.
4/19/01	2.1	• Updated values in **Virtex-E Switching Characteristics** tables.

Pinout Differences Between Virtex and Virtex-E Families

The same device in the same package for the Virtex-E and Virtex families are pin-compatible with some minor exceptions, listed in Table 1.

XCV200E Device, FG456 Package

The Virtex-E XCV200E has two I/O pins swapped with the Virtex XCV200 to accommodate differential clock pairing.

XCV400E Device, FG676 Package

The Virtex-E XCV400E has two I/O pins swapped with the Virtex XCV400 to accommodate differential clock pairing.

All Devices, PQ240 and HQ240 Packages

The Virtex devices in PQ240 and HQ240 packages do not have V_{CCO} banking, but Virtex-E devices do. To achieve this, eight Virtex I/O pins (P232, P207, P176, P146, P116, P85, P55, and P25) are now VCCO pins in the Virtex-E family. This change also requires one Virtex I/O or VREF pin to be swapped with a standard I/O pin.

Additionally, accommodating differential clock input pairs in Virtex-E caused some IO_V_{REF} differences in the XCV400E and XCV600E devices only. Virtex IO_V_{REF} pins P215 and P87 are Virtex-E IO_V_{REF} pins P216 and P86, respectively. Virtex-E pins P215 and P87 are IO_DLL.

Table 1: **Pinout Differences Summary**

Part	Package	Pins	Virtex	Virtex-E
XCV200	FG456	E11, U11	I/O	No Connect
		B11, AA11	No Connect	IO_LVDS_DLL
XCV400	FG676	D13, Y13	I/O	No Connect
		B13, AF13	No Connect	IO_LVDS_DLL
XCV400/600	PQ240/HQ240	P215, P87	IO_V_{REF}	IO_LVDS_DLL
		P216, P86	I/O	IO_V_{REF}
All	PQ240/HQ240	P232, P207, P176, P146, P116, P85, P55, and P25	I/O	V_{CCO}
		P231	I/O	IO_V_{REF}

Table 10: **BG352 — XCV100E, XCV200E, XCV300E**

Bank	Pin Description	Pin #
0	IO	C15
0	IO	B15[1]
0	IO_LVDS_DLL_L9N	A15
0	GCK3	D14
1	GCK2	B14
1	IO_LVDS_DLL_L9P	A13
1	IO	B13[1]
1	IO_L10N	C13
1	IO_L10P	A12
1	IO_L11N_Y	B12
1	IO_VREF_1_L11P_Y	C12
1	IO_L12N_Y	A11
1	IO_L12P_Y	B11
1	IO	B10[1]
1	IO_L13N	C11
1	IO_L13P	D11
1	IO	A9[1]
1	IO_L14N_YY	B9
1	IO_L14P_YY	C10
1	IO_L15N_YY	B8
1	IO_VREF_1_L15P_YY	C9
1	IO_L16N _Y	D9
1	IO_L16P _Y	A7
1	IO	B7
1	IO	C8[1]
1	IO	D8[1]
1	IO_L17N_YY	A6
1	IO_VREF_1_L17P_YY	B6
1	IO_L18N_YY	C7
1	IO_L18P_YY	A4
1	IO	B5[1]
1	IO_L19N_YY	C6
1	IO_VREF_1_L19P_YY	D6[2]

Table 10: **BG352 — XCV100E, XCV200E, XCV300E**

Bank	Pin Description	Pin #
1	IO	B4
1	IO	C5[1]
1	IO	A3[1]
1	IO_WRITE_L20N_YY	D5
1	IO_CS_L20P_YY	C4
2	IO_DOUT_BUSY_L21P_YY	E4
2	IO_DIN_D0_L21N_YY	D3
2	IO	C2[1]
2	IO	E3[1]
2	IO	F4
2	IO_VREF_2_L22P_YY	D2[2]
2	IO_L22N_YY	C1
2	IO	D1[1]
2	IO_L23P_YY	G4
2	IO_L23N_YY	F3
2	IO_VREF_2_L24P_Y	E2
2	IO_L24N_Y	F2
2	IO	G3[1]
2	IO	G2[1]
2	IO_L25P	F1
2	IO_L25N	J4
2	IO	H3
2	IO_VREF_2_L26P _Y	H2
2	IO_D1_L26N _Y	G1
2	IO_D2_L27P_YY	J3
2	IO_L27N_YY	J2
2	IO	K3[1]
2	IO_L28P	J1
2	IO_L28N	L4
2	IO	K2[1]
2	IO_L29P_YY	L3
2	IO_L29N_YY	L2
2	IO_VREF_2_L30P _Y	M4

Table 10: **BG352 — XCV100E, XCV200E, XCV300E**

Bank	Pin Description	Pin #
NA	VCCINT	V24
NA	VCCINT	R23
NA	VCCINT	P25
NA	VCCINT	L25
NA	VCCINT	J24
0	VCCO	D19
0	VCCO	B25
0	VCCO	A17
1	VCCO	D13
1	VCCO	D7
1	VCCO	A10
2	VCCO	K1
2	VCCO	H4
2	VCCO	B2
3	VCCO	Y4
3	VCCO	U1
3	VCCO	P4
4	VCCO	AF10
4	VCCO	AE2
4	VCCO	AC8
5	VCCO	AF17
5	VCCO	AC20
5	VCCO	AC14
6	VCCO	AE25
6	VCCO	W23
6	VCCO	U26
7	VCCO	N23
7	VCCO	K26
7	VCCO	G23
NA	GND	A26
NA	GND	A25
NA	GND	A22

Table 10: **BG352 — XCV100E, XCV200E, XCV300E**

Bank	Pin Description	Pin #
NA	GND	A19
NA	GND	A14
NA	GND	A8
NA	GND	A5
NA	GND	A2
NA	GND	A1
NA	GND	B26
NA	GND	B1
NA	GND	E26
NA	GND	E1
NA	GND	H26
NA	GND	H1
NA	GND	N1
NA	GND	P26
NA	GND	W26
NA	GND	W1
NA	GND	AB26
NA	GND	AB1
NA	GND	AE26
NA	GND	AE1
NA	GND	AF26
NA	GND	AF25
NA	GND	AF22
NA	GND	AF19
NA	GND	AF13
NA	GND	AF8
NA	GND	AF5
NA	GND	AF2
NA	GND	AF1

Notes:
1. No Connect in the XCV100E.
2. V_{REF} or I/O option only in the XCV200E and XCV300E; otherwise, I/O option only.

Table 14: **BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin#	See Note
4	IO_L104N_YY	AJ12	
4	IO_L105P_Y	AN11	
4	IO_L105N_Y	AK12	
4	IO_L106P_YY	AL12	
4	IO_L106N_YY	AM12	
4	IO_VREF_L107P_YY	AK13	3
4	IO_L107N_YY	AL13	
4	IO_L108P_Y	AM13	
4	IO_L108N_Y	AN13	
4	IO_L109P_YY	AJ14	
4	IO_L109N_YY	AK14	
4	IO_VREF_L110P_YY	AM14	
4	IO_L110N_YY	AN15	
4	IO_L111P_Y	AJ15	
4	IO_L111N_Y	AK15	
4	IO_L112P_Y	AL15	
4	IO_L112N_Y	AM16	
4	IO_VREF_L113P_Y	AL16	
4	IO_L113N_Y	AJ16	
4	IO_L114P_Y	AK16	
4	IO_VREF_L114N_Y	AN17	2
4	IO_LVDS_DLL_L115P	AM17	
5	GCK1	AJ17	
5	IO	AL25	
5	IO	AL28	
5	IO	AL30	
5	IO	AN28	
5	IO_LVDS_DLL_L115N	AM18	
5	IO_VREF	AL18	2
5	IO_L116P_Y	AK18	
5	IO_VREF_L116N_Y	AJ18	
5	IO_L117P_Y	AN19	
5	IO_L117N_Y	AL19	
5	IO_L118P_Y	AK19	

Table 14: **BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin#	See Note
5	IO_L118N_Y	AM20	
5	IO_L119P_YY	AJ19	
5	IO_VREF_L119N_YY	AL20	
5	IO_L120P_YY	AN21	
5	IO_L120N_YY	AL21	
5	IO_L121P_Y	AJ20	
5	IO_L121N_Y	AM22	
5	IO_L122P_YY	AK21	
5	IO_VREF_L122N_YY	AN23	3
5	IO_L123P_YY	AJ21	
5	IO_L123N_YY	AM23	
5	IO_L124P_Y	AK22	
5	IO_L124N_Y	AM24	
5	IO_L125P_YY	AL23	
5	IO_L125N_YY	AJ22	
5	IO_L126P_YY	AK23	
5	IO_VREF_L126N_YY	AL24	
5	IO_L127P_Y	AN26	
5	IO_L127N_Y	AJ23	
5	IO_L128P_Y	AK24	
5	IO_VREF_L128N_Y	AM26	4
5	IO_L129P_Y	AM27	
5	IO_L129N_Y	AJ24	
5	IO_L130P_Y	AL26	
5	IO_VREF_L130N_Y	AK25	1
5	IO_L131P_YY	AN29	
5	IO_VREF_L131N_YY	AJ25	
5	IO_L132P_YY	AK26	
5	IO_L132N_YY	AM29	
5	IO_L133P_Y	AM30	
5	IO_L133N_Y	AJ26	
5	IO_L134P_YY	AK27	
5	IO_VREF_L134N_YY	AL29	
5	IO_L135P_YY	AN31	
5	IO_L135N_YY	AJ27	

Table 17: **FG256 Differential Pin Pair Summary XCV50E, XCV100E, XCV200E, XCV300E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
19	2	C15	D14	√	DIN, D0
20	2	B16	E13	6	VREF
21	2	C16	E14	√	-
22	2	F13	E15	1	VREF
23	2	F12	D16	5	-
24	2	F14	E16	3	D1
25	2	F15	G13	√	D2
26	2	F16	G12	6	-
27	2	G15	G14	√	-
28	2	H13	G16	3	D3
29	2	J13	H15	4	-
30	2	H14	H16	√	-
31	3	K15	J14	4	-
32	3	J16	K16	3	VREF
33	3	K12	L15	√	-
34	3	K13	L16	6	-
35	3	K14	M16	√	D5
36	3	N16	L13	3	VREF
37	3	P16	L12	5	-
38	3	M15	L14	1	VREF
39	3	M14	R16	√	-
40	3	M13	T15	6	VREF
41	3	N14	N15	√	INIT
42	4	T14	P13	√	-
43	4	P12	R13	7	VREF
44	4	N12	T13	√	-
45	4	T12	P11	√	VREF
46	4	R12	N11	2	-
47	4	T11	M11	√	VREF
48	4	R11	T10	√	-
49	4	R10	M10	1	-
50	4	P9	T9	1	VREF
51	4	N10	R9	1	-
52	5	N9	T8	NA	IO_LVDS_DLL
53	5	R7	P8	1	VREF
54	5	P7	T6	1	-

Table 17: **FG256 Differential Pin Pair Summary XCV50E, XCV100E, XCV200E, XCV300E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
55	5	M7	R6	√	-
56	5	P6	R5	√	VREF
57	5	N6	T5	2	-
58	5	M6	T4	√	VREF
59	5	T3	P5	√	-
60	5	T2	N5	7	VREF
61	6	R1	M3	√	-
62	6	N2	M4	6	VREF
63	6	P1	L5	√	-
64	6	L3	N1	1	VREF
65	6	L4	M2	5	-
66	6	K4	M1	3	VREF
67	6	L1	L2	√	-
68	6	K1	K3	6	-
69	6	K5	K2	√	-
70	6	J1	J3	3	VREF
71	6	H1	J4	4	-
72	7	H4	G1	√	-
73	7	H2	G5	4	-
74	7	H3	G4	3	VREF
75	7	F5	G2	√	-
76	7	F1	F4	6	-
77	7	F2	G3	√	-
78	7	D1	E1	3	VREF
79	7	E2	E4	5	-
80	7	C1	F3	1	VREF
81	7	E3	D2	√	-
82	7	A2	B1	6	VREF

Notes:
1. AO in the XCV50E, 200E, 300E.
2. AO in the XCV50E, 200E.
3. AO in the XCV50E, 300E.
4. AO in the XCV100E, 200E.
5. AO in the XCV200E.
6. AO in the XCV100E.
7. AO in the XCV50E.

Table 19: **FG456 Differential Pin Pair Summary XCV200E, XCV300E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
88	5	V7	AB3	√	-
89	6	Y2	W3	√	-
90	6	V3	V4	√	-
91	6	U4	Y1	√	VREF
92	6	W1	V2	√	-
93	6	U2	T3	√	VREF
94	6	V1	T5	2	-
95	6	U1	R5	1	-
96	6	T1	R4	2	VREF
97	6	P3	R2	√	-
98	6	R1	P5	√	-
99	6	N5	P2	√	-
100	6	N4	P1	2	-
101	6	N2	N3	1	VREF
102	6	M4	N1	2	-
103	6	M6	M3	√	-
104	7	L4	L3	√	-
105	7	L1	L5	√	-
106	7	K2	L6	2	-
107	7	K3	K4	2	VREF
108	7	K5	K1	√	-
109	7	J2	J3	√	-
110	7	H1	J5	√	-
111	7	H3	H2	√	-
112	7	H4	G1	2	VREF
113	7	F2	F1	2	-
114	7	G3	H5	√	-
115	7	E2	E1	√	VREF
116	7	G5	F3	√	-
117	7	D2	E3	√	VREF
118	7	C1	F5	√	-

Notes:
1. AO in the XCV200E.
2. AO in the XCV300E.

FG676 Fine-Pitch Ball Grid Array Package

XCV400E and XCV600E devices in the FG676 fine-pitch Ball Grid Array package have footprint compatibility. Pins labeled I0_VREF can be used as either in all parts unless device-dependent as indicated in the footnotes. If the pin is not used as V_{REF}, it can be used as general I/O. Immediately following Table 20, see Table 21 for Differential Pair information.

Table 20: **FG676 — XCV400E, XCV600E**

Bank	Pin Description	Pin #
0	GCK3	E13
0	IO	A6
0	IO	A9[1]
0	IO	A10[1]
0	IO	B3
0	IO	B4[1]
0	IO	B12[1]
0	IO	C6
0	IO	C8
0	IO	D5
0	IO	D13[1]
0	IO	G13
0	IO_L0N_Y	C4
0	IO_L0P_Y	F7
0	IO_L1N_YY	G8
0	IO_L1P_YY	C5
0	IO_VREF_L2N_YY	D6
0	IO_L2P_YY	E7
0	IO_L3N	A4
0	IO_L3P	F8
0	IO_L4N	B5
0	IO_L4P	D7
0	IO_VREF_L5N_YY	E8
0	IO_L5P_YY	G9
0	IO_L6N_YY	A5
0	IO_L6P_YY	F9
0	IO_L7N_Y	D8
0	IO_L7P_Y	C7
0	IO_VREF_L8N_Y	B7[2]
0	IO_L8P_Y	E9

Table 22: **FG680 - XCV600E, XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin #
0	VCCO	E34
0	VCCO	E33
0	VCCO	E30
0	VCCO	E29
0	VCCO	E27
0	VCCO	E26
1	VCCO	E10
1	VCCO	E11
1	VCCO	E13
1	VCCO	E14
1	VCCO	E6
1	VCCO	E7
2	VCCO	P5
2	VCCO	N5
2	VCCO	L5
2	VCCO	K5
2	VCCO	G5
2	VCCO	F5
3	VCCO	AP5
3	VCCO	AN5
3	VCCO	AK5
3	VCCO	AJ5
3	VCCO	AG5
3	VCCO	AF5
4	VCCO	AR10
4	VCCO	AR11
4	VCCO	AR13
4	VCCO	AR14
4	VCCO	AR6
4	VCCO	AR7
5	VCCO	AR34
5	VCCO	AR33
5	VCCO	AR30
5	VCCO	AR29
5	VCCO	AR27
5	VCCO	AR26
6	VCCO	AP35
6	VCCO	AN35
6	VCCO	AK35
6	VCCO	AJ35
6	VCCO	AG35
6	VCCO	AF35
7	VCCO	P35
7	VCCO	N35
7	VCCO	L35
7	VCCO	K35
7	VCCO	G35
7	VCCO	F35
NA	GND	Y5
NA	GND	Y4
NA	GND	Y37
NA	GND	Y36
NA	GND	Y35
NA	GND	Y3
NA	GND	W5
NA	GND	W35
NA	GND	M5
NA	GND	M4
NA	GND	M36
NA	GND	M35
NA	GND	E5
NA	GND	E35
NA	GND	E28
NA	GND	E21
NA	GND	E20
NA	GND	E19
NA	GND	E12
NA	GND	D4
NA	GND	D36
NA	GND	D28

Table 24: **FG860 — XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin #
6	IO_VREF_L245N_Y	AB40[1]
6	IO_L245P_Y	AC39
7	IO	F38
7	IO	H40
7	IO	H41
7	IO	J42
7	IO	K39
7	IO	L42
7	IO	N40
7	IO	T40
7	IO	U40
7	IO	V38
7	IO	W42
7	IO	Y42
7	IO	AA42
7	IO_L246N_YY	AA41
7	IO_L246P_YY	AB39
7	IO_L247N_Y	Y41
7	IO_VREF_L247P_Y	AA39[1]
7	IO_L248N_YY	Y40
7	IO_L248P_YY	Y39
7	IO_L249N_YY	Y38
7	IO_VREF_L249P_YY	W41
7	IO_L250N_Y	W40
7	IO_L250P_Y	W39
7	IO_L251N_Y	W38
7	IO_L251P_Y	V41
7	IO_L252N_YY	V39
7	IO_L252P_YY	V40
7	IO_L253N_YY	V42
7	IO_VREF_L253P_YY	U39
7	IO_L254N_Y	U41
7	IO_L254P_Y	U38
7	IO_L255N_Y	U42
7	IO_L255P_Y	T39
7	IO_L256N_YY	T41

Table 24: **FG860 — XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin #
7	IO_L256P_YY	T38
7	IO_L257N_Y	R39
7	IO_VREF_L257P_Y	T42
7	IO_L258N_Y	R42
7	IO_L258P_Y	R38
7	IO_L259N	R40
7	IO_L259P	P39
7	IO_L260N_Y	R41
7	IO_L260P_Y	P38
7	IO_L261N_Y	P42
7	IO_L261P_Y	N39
7	IO_L262N_Y	P40
7	IO_L262P_Y	M39
7	IO_L263N_YY	P41
7	IO_L263P_YY	M38
7	IO_L264N_YY	N42
7	IO_VREF_L264P_YY	L39
7	IO_L265N_Y	L38
7	IO_L265P_Y	N41
7	IO_L266N_YY	K40
7	IO_L266P_YY	M42
7	IO_L267N_YY	M40
7	IO_VREF_L267P_YY	K38
7	IO_L268N_Y	M41
7	IO_L268P_Y	J40
7	IO_L269N_Y	J39
7	IO_VREF_L269P_Y	L40
7	IO_L270N_YY	J38
7	IO_L270P_YY	L41
7	IO_L271N_YY	K42
7	IO_VREF_L271P_YY	H39
7	IO_L272N_Y	K41
7	IO_L272P_Y	H38
7	IO_L273N_Y	J41
7	IO_L273P_Y	G40
7	IO_L274N_YY	H42
7	IO_L274P_YY	G39

Table 25: **FG860 Differential Pin Pair Summary**
XCV1000E, XCV1600E, XCV2000E

Pair	Bank	P Pin	N Pin	AO	Other Functions
52	1	D11	B15	√	VREF
53	1	C14	E11	2	-
54	1	B14	C10	2	-
55	1	E10	A13	√	VREF
56	1	C9	C13	√	-
57	1	A12	D9	1	VREF
58	1	C12	E9	1	-
59	1	D8	B12	√	VREF
60	1	E8	A11	√	-
61	1	A10	C7	5	-
62	1	B10	C6	5	-
63	1	B9	A9	√	VREF
64	1	E7	A8	√	-
65	1	C5	B8	5	-
66	1	A6	A7	1	VREF
67	1	D6	B7	1	-
68	1	C4	A5	2	-
69	1	E6	B6	√	CS
70	2	F5	D2	√	DIN, D0
71	2	E4	E2	3	-
72	2	D3	F2	1	-
73	2	E1	F4	2	VREF
74	2	G2	E3	4	-
75	2	F1	G5	2	-
76	2	G1	F3	1	VREF
77	2	G4	H1	√	-
78	2	J2	G3	2	-
79	2	H5	K2	1	-
80	2	H4	K1	√	VREF
81	2	L2	L3	√	-
82	2	L1	J5	5	VREF
83	2	J4	M3	2	-
84	2	J3	M1	√	VREF
85	2	N2	K4	√	-

Table 25: **FG860 Differential Pin Pair Summary**
XCV1000E, XCV1600E, XCV2000E

Pair	Bank	P Pin	N Pin	AO	Other Functions
86	2	N3	K3	2	-
87	2	L5	P2	√	D1
88	2	P3	L4	√	D2
89	2	P1	R2	3	-
90	2	M5	R3	1	-
91	2	M4	R1	2	-
92	2	N4	T2	4	-
93	2	P5	T3	2	-
94	2	P4	T1	1	VREF
95	2	U2	R4	√	-
96	2	U3	T5	2	-
97	2	T4	V2	1	-
98	2	U5	V3	√	D3
99	2	V1	V5	√	-
100	2	W2	V4	5	-
101	2	W5	W1	2	-
102	2	Y2	W4	√	VREF
103	2	Y1	Y5	√	-
104	2	AA1	Y4	2	VREF
105	2	AA4	AA2	√	-
106	3	AB3	AC4	2	VREF
107	3	AB1	AC5	√	-
108	3	AD4	AC3	√	VREF
109	3	AC1	AD5	2	-
110	3	AE4	AD3	5	-
111	3	AE5	AD2	√	-
112	3	AE1	AF5	√	VREF
113	3	AE2	AG4	1	-
114	3	AG5	AF1	2	-
115	3	AH4	AF2	√	-
116	3	AF3	AJ4	1	VREF
117	3	AG1	AJ5	2	-
118	3	AG2	AK4	4	-
119	3	AG3	AL4	2	-

Table 26: **FG900 — XCV600E, XCV1000E, XCV1600E**

Bank	Pin Description	Pin #
3	IO_L127P_YY	Y24
3	IO_VREF_L127N_YY	AB28
3	IO_L128P_YY	AC30
3	IO_L128N_YY	AA25
3	IO_L129P	W21
3	IO_L129N	AA24
3	IO_L130P_YY	AB26
3	IO_L130N_YY	AD30
3	IO_L131P_YY	Y22
3	IO_VREF_L131N_YY	AC27
3	IO_L132P	AD28
3	IO_L132N	AB25
3	IO_L133P_YY	AC26
3	IO_L133N_YY	AE30
3	IO_L134P_YY	AD27
3	IO_L134N_YY	AF30
3	IO_L135P	AF29
3	IO_VREF_L135N	AB24
3	IO_L136P_YY	AB23
3	IO_L136N_YY	AE28
3	IO_L137P_Y	AG30[3]
3	IO_L137N_Y	AC25[4]
3	IO_L138P_YY	AE26
3	IO_VREF_L138N_YY	AG29[1]
3	IO_L139P	AH30
3	IO_L139N	AC24
3	IO_L140P	AF28[3]
3	IO_L140N	AD25[4]
3	IO_D7_L141P_YY	AH29
3	IO_INIT_L141N_YY	AA22
4	GCK0	AJ16
4	IO	AB19[4]
4	IO	AC16[4]
4	IO	AC19
4	IO	AD18[4]
4	IO	AD21[4]

Table 26: **FG900 — XCV600E, XCV1000E, XCV1600E**

Bank	Pin Description	Pin #
4	IO	AE15[4]
4	IO	AE18[4]
4	IO	AE21
4	IO	AE24[5]
4	IO	AF17[5]
4	IO	AF18[5]
4	IO	AJ18[4]
4	IO	AK18
4	IO	AK25[5]
4	IO	AK27[4]
4	IO	AH23[4]
4	IO	AH24[5]
4	IO_L142P_YY	AF27
4	IO_L142N_YY	AK28
4	IO_L143P_YY	AG26[4]
4	IO_L143N_YY	AH27[3]
4	IO_L144P	AD23
4	IO_L144N	AJ27
4	IO_VREF_L145P	AB21[1]
4	IO_L145N	AF25
4	IO_L146P	AC22[4]
4	IO_L146N	AH26[4]
4	IO_L147P_YY	AA21
4	IO_L147N_YY	AG25
4	IO_VREF_L148P_YY	AJ26
4	IO_L148N_YY	AD22
4	IO_L149P	AA20
4	IO_L149N	AH25
4	IO_L150P	AC21
4	IO_L150N	AF24
4	IO_L151P_YY	AG24
4	IO_L151N_YY	AK26
4	IO_VREF_L152P_YY	AJ24
4	IO_L152N_YY	AF23
4	IO_L153P	AE23
4	IO_L153N	AB20
4	IO_L154P	AC20

Table 26: **FG900 — XCV600E, XCV1000E, XCV1600E**

Bank	Pin Description	Pin #
7	IO_L275N_YY	G3
7	IO_L275P_YY	E1
7	IO_L276N_YY	H6
7	IO_L276P_YY	E2
7	IO_L277N	E4
7	IO_VREF_L277P	K9
7	IO_L278N_YY	J8
7	IO_L278P_YY	F4
7	IO_L279N_Y	D1[3]
7	IO_L279P_Y	H7[4]
7	IO_L280N_YY	G6
7	IO_VREF_L280P_YY	C2[1]
7	IO_L281N	D2
7	IO_L281P	F5
7	IO_L282N_YY	D3[4]
7	IO_L282P_YY	K10[3]
2	CCLK	F26
3	DONE	AJ28
NA	DXN	AJ3
NA	DXP	AH4
NA	M0	AF4
NA	M1	AC7
NA	M2	AK3
NA	PROGRAM	AG28
NA	TCK	B3
NA	TDI	H22
2	TDO	D26
NA	TMS	C1
NA	VCCINT	L11
NA	VCCINT	L12
NA	VCCINT	L19
NA	VCCINT	L20
NA	VCCINT	M11
NA	VCCINT	M12
NA	VCCINT	M19

Table 26: **FG900 — XCV600E, XCV1000E, XCV1600E**

Bank	Pin Description	Pin #
NA	VCCINT	M20
NA	VCCINT	N13
NA	VCCINT	N14
NA	VCCINT	N15
NA	VCCINT	N16
NA	VCCINT	N17
NA	VCCINT	N18
NA	VCCINT	P13
NA	VCCINT	P18
NA	VCCINT	R13
NA	VCCINT	R18
NA	VCCINT	T13
NA	VCCINT	T18
NA	VCCINT	U13
NA	VCCINT	U18
NA	VCCINT	V13
NA	VCCINT	V14
NA	VCCINT	V15
NA	VCCINT	V16
NA	VCCINT	V17
NA	VCCINT	V18
NA	VCCINT	W11
NA	VCCINT	W12
NA	VCCINT	W19
NA	VCCINT	W20
NA	VCCINT	Y11
NA	VCCINT	Y12
NA	VCCINT	Y19
NA	VCCINT	Y20
NA	VCCO_0	B6
NA	VCCO_0	M15
NA	VCCO_0	M14
NA	VCCO_0	L15
NA	VCCO_0	L14
NA	VCCO_0	H14
NA	VCCO_0	M13

Table 28: **FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Bank	Pin Description	Pin #
0	IO_L40P_Y	A17
0	IO_VREF_L41N_Y	G17[1]
0	IO_L41P_Y	B17
0	IO_LVDS_DLL_L42N	C17
1	GCK2	D17
1	IO	A18
1	IO	B18[3]
1	IO	B24
1	IO	B25
1	IO	E22[3]
1	IO	E23[3]
1	IO	D18[3]
1	IO	D19
1	IO	D25[3]
1	IO	D26[3]
1	IO	D28[3]
1	IO	D29[3]
1	IO	G23[3]
1	IO	J23[3]
1	IO_LVDS_DLL_L42P	J18
1	IO_L43N_Y	G18
1	IO_VREF_L43P_Y	C18[1]
1	IO_L44N_Y	H18
1	IO_L44P_Y	F18
1	IO_L45N_YY	B19
1	IO_VREF_L45P_YY	A19
1	IO_L46N_YY	K19
1	IO_L46P_YY	C19
1	IO_L47N	F19[5]
1	IO_L47P	E19[4]
1	IO_L48N_Y	G19
1	IO_L48P_Y	J19
1	IO_L49N_Y	A20

Table 28: **FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Bank	Pin Description	Pin #
1	IO_L49P_Y	G20
1	IO_L50N	B20[5]
1	IO_L50P	F20[4]
1	IO_L51N_YY	D20
1	IO_VREF_L51P_YY	E20
1	IO_L52N_YY	H20
1	IO_L52P_YY	A21
1	IO_L53N	E21[5]
1	IO_L53P	J20[4]
1	IO_L54N_Y	D21
1	IO_L54P_Y	K20
1	IO_L55N_Y	B21
1	IO_L55P_Y	H21
1	IO_L56N_YY	G21[5]
1	IO_L56P_YY	F21[4]
1	IO_L57N_YY	A22
1	IO_VREF_L57P_YY	B22
1	IO_L58N_YY	J21
1	IO_L58P_YY	C22
1	IO_L59N_Y	D22
1	IO_L59P_Y	G22
1	IO_L60N_Y	K21
1	IO_L60P_Y	A23
1	IO_L61N_Y	F22
1	IO_L61P_Y	B23
1	IO_L62N_Y	C23
1	IO_L62P_Y	H22
1	IO_L63N_YY	D23
1	IO_L63P_YY	K22
1	IO_L64N_YY	A24
1	IO_VREF_L64P_YY	J22
1	IO_L65N_Y	H23
1	IO_L65P_Y	D24
1	IO_L66N_Y	A25

FG1156 Differential Pin Pairs

Virtex-E devices have differential pin pairs that can also provide other functions when not used as a differential pair. The AO column in Table 29 indicates which devices in this package can use the pin pair as an asynchronous output. The "Other Functions" column indicates alternative function(s) that are not available when the pair is used as a differential pair or differential clock.

Table 29: **FG1156 Differential Pin Pair Summary: XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
GCLK LVDS					
3	0	E17	C17	NA	IO_DLL_L 42N
2	1	D17	J18	NA	IO_DLL_L 42P
1	5	AL19	AL17	NA	IO_DLL_L 215N
0	4	AH18	AM18	NA	IO_DLL_L 215P
IO LVDS Total Pairs: 344, Asynchronous Output Pairs: 134					
0	0	H9	F7	3200 1600 1000	-
1	0	J10	C5	3200 2000 1000	-
2	0	D6	E6	3200 2000 1000	VREF
3	0	G8	A4	3200 2600 1000	-
4	0	J11	C6	3200 2600 2000 1600 1000	-
5	0	F8	G9	3200 2600 2000 1600 1000	VREF
6	0	H10	A5	2000 1600	-
7	0	B5	D7	3200 1000	-
8	0	E8	K12	3200 1000	-
9	0	F9	B6	3200 2600	-
10	0	C7	G10	3200 2600 2000 1600 1000	-
11	0	B7	D8	3200 2600 2000 1600 1000	VREF
12	0	C8	H11	3200 1600	-
13	0	B8	E9	3200 2000 1000	-
14	0	G11	K13	3200 2000 1000	VREF
15	0	F10	A8	3200 2600	-
16	0	H12	C9	3200 2600 2000 1600 1000	-
17	0	A9	D10	3200 2600 2000 1600 1000	VREF
18	0	A10	F11	2600 1600 1000	-
19	0	C10	K14	2600 1600 1000	-
20	0	G12	H13	3200 2600 2000 1600 1000	VREF
21	0	B11	A11	3200 2600 2000 1600 1000	-
22	0	D11	E12	3200 1600 1000	-
23	0	C12	G13	3200 2000 1000	-
24	0	A12	K15	3200 2000 1000	-
25	0	H14	B12	3200 2600 1000	-
26	0	F13	D12	3200 2600 2000 1600 1000	-
27	0	B13	A13	3200 2600 2000 1600 1000	VREF
28	0	G14	J15	2000 1600	-
29	0	F14	C13	3200 2600 1000	-
30	0	D13	H15	3200 2600 1000	-
31	0	K16	A14	3200	-